

SB25150CT - SB25200CT

25A HIGH VOLTAGE DUAL SCHOTTKY BARRIER RECTIFIER

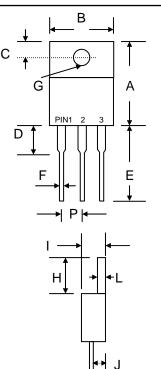


Features

- Schottky Barrier Chip
- Guard Ring for Transient Protection
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Current Capability
- Epoxy Meets UL 94V-0 Classification
- Ideally Suited for Use in High Frequency SMPS, Inverters and As Free Wheeling Diodes

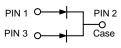
Mechanical Data

- Case: TO-220, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 1.9 grams (approx.)
- Mounting Position: Any
- Mounting Torque: 0.6 N.m Max.
- Lead Free: For RoHS / Lead Free Version, Add "-LF" Suffix to Part Number, See Page 4



Κ

TO-220				
Dim	Min	Max		
Α	13.90	15.90		
В	9.80	10.70		
С	2.54	3.43		
D	3.56	4.56		
Е	12.70	14.73		
F	0.51	0.96		
G	3.55 Ø	4.09 Ø		
н	5.75	6.85		
I	4.16	5.00		
J	2.03	2.92		
К	0.30	0.65		
L	1.14	1.40		
Р	2.29	2.79		
All Dimensions in mm				



Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

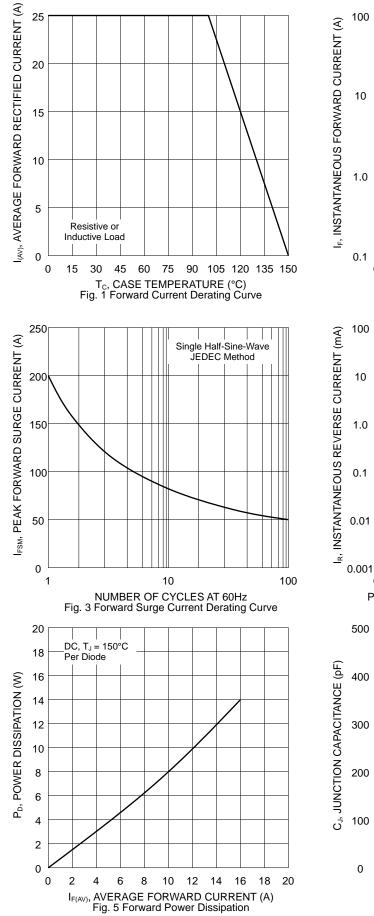
Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

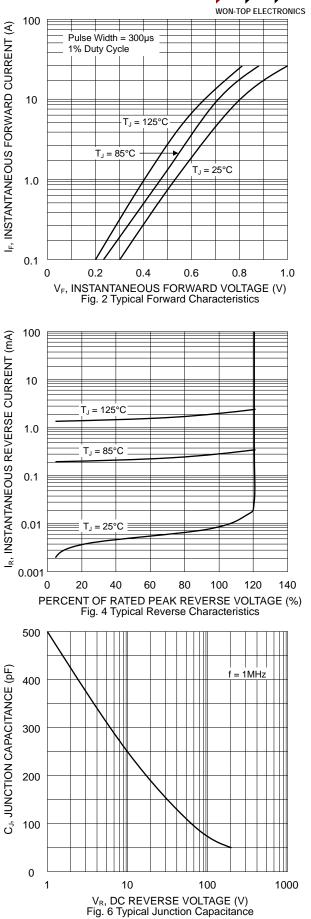
Characteristic	Symbol	SB25150CT	SB25200CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	150	200	V
RMS Reverse Voltage	VR(RMS)	105	140	V
Average Rectified Output CurrentTotal Device $@T_c = 100^{\circ}C$ Per Diode	lo		5 2.5	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	IFSM	2(00	A
Forward Voltage per diode $@I_F = 12.5A, T_J = 25^{\circ}C$ $@I_F = 12.5A, T_J = 125^{\circ}C$	Vfm	••	92 82	V
Peak Reverse Current $@T_J = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_J = 100^{\circ}C$	IRM	0 1	.5 0	mA
Typical Junction Capacitance (Note 1)	CJ	3	50	pF
Thermal Resistance Junction to Ambient per diode Thermal Resistance Junction to Case per diode	R JA R JC	55 1.5		°C/W
Operating and Storage Temperature Range	TJ, Tsтg	-55 to +150		°C

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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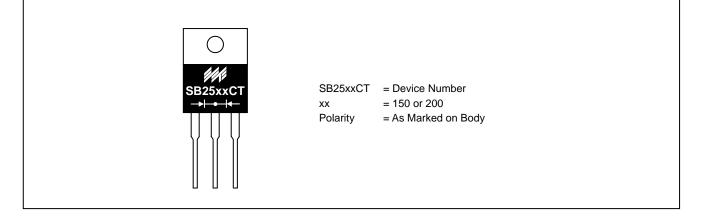


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MARKING INFORMATION



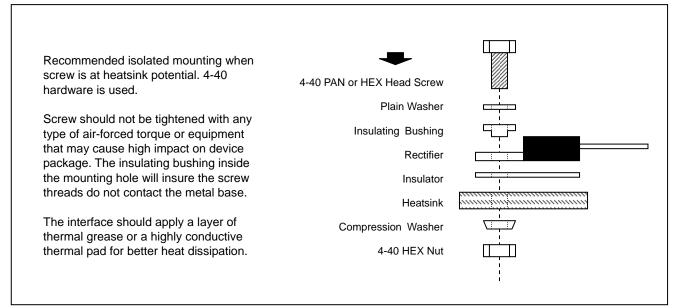
PACKAGING INFORMATION

BULK

Tube Size	Quantity	Inner Box Size	Quantity	Carton Size	Quantity	Approx. Gross Weight
L x W x H (mm)	(PCS)	L x W x H (mm)	(PCS)	L x W x H (mm)	(PCS)	(KG)
525 x 31 x 6	50	555 x 145 x 95	2,000	572 x 306 x 218	8,000	19.0

Note: 1. Anti-static tube, water clear color.

RECOMMENDED SCREW MOUNTING ARRANGEMENT





Product No.	Package Type	Shipping Quantity
SB25150CT	TO-220	50 Units/Tube
SB25200CT	TO-220	50 Units/Tube

ORDERING INFORMATION

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.
To order RoHS / Lead Free version (with Lead Free finish), add "-LF"

suffix to part number above. For example, SB25150CT-LF.

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